NCE N-Channel Enhancement Mode Power MOSFET

Description

The NCE0260 uses advanced trench technology and design to provide excellent $R_{DS(ON)}$ with low gate charge. It can be used in a wide variety of applications.

General Features

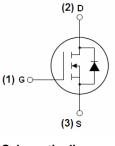
- V_{DS} =200V, I_{D} =60A $R_{DS(ON)}$ <32m Ω @ V_{GS} =10V
- High density cell design for ultra low Rdson
- Fully characterized avalanche voltage and current
- Good stability and uniformity with high E_{AS}
- Excellent package for good heat dissipation
- Special process technology for high ESD capability

Application

- Power switching application
- Hard switched and high frequency circuits
- Uninterruptible power supply

100% UIS TESTED!

100% ΔVds TESTED!



Schematic diagram



Marking and pin assignment



TO-220-3L top view

Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCE0260	NCE0260	TO-220-3L	-	-	-

Absolute Maximum Ratings (T_C=25 ℃unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V _{DS}	200	V
Gate-Source Voltage	V _G S	±20	V
Drain Current-Continuous	I _D	60	Α
Drain Current-Continuous(T _C =100 °C)	I _D (100℃)	42	Α
Pulsed Drain Current	I _{DM}	280	Α
Maximum Power Dissipation	P _D	285	W
Derating factor		1.9	W/℃
Single pulse avalanche energy (Note 5)	E _{AS}	225	mJ
Operating Junction and Storage Temperature Range	T_{J}, T_{STG}	-55 To 175	$^{\circ}$



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Thermal Characteristic

Thermal Resistance, Junction-to-Case (Note 2)	$R_{ heta JC}$	0.53	°C/W	Ī
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Electrical Characteristics (T_C=25 °C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics	•					
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =250μA	200	220	-	V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =200V,V _{GS} =0V	-	-	1	μA
Gate-Body Leakage Current	I _{GSS}	V _{GS} =±20V,V _{DS} =0V	-	-	±100	nA
On Characteristics (Note 3)						
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$, $I_{D}=250\mu A$	2	3.2	4	V
Drain-Source On-State Resistance	R _{DS(ON)}	V _{GS} =10V, I _D =20A	-	24	32	mΩ
Forward Transconductance	g FS	V _{DS} =5V,I _D =30A	40	-	-	S
Dynamic Characteristics (Note4)						
Input Capacitance	C _{lss}	\/ 50\/\/ 0\/	-	6200	-	PF
Output Capacitance	Coss	V_{DS} =50V, V_{GS} =0V, F=1.0MHz	-	950	-	PF
Reverse Transfer Capacitance	C _{rss}	F=1.0WHZ	-	460	-	PF
Switching Characteristics (Note 4)						
Turn-on Delay Time	t _{d(on)}		-	33	-	nS
Turn-on Rise Time	t _r	V_{DD} =100V, R_{L} =15 Ω	-	20	-	nS
Turn-Off Delay Time	t _{d(off)}	V_{GS} =10V, R_{G} =2.5 Ω	-	21	-	nS
Turn-Off Fall Time	t _f		-	31	-	nS
Total Gate Charge	Q_g	\/ -100\/ -20 \	-	130		nC
Gate-Source Charge	Q _{gs}	V_{DS} =100V, I_{D} =30A, V_{GS} =10V	-	36		nC
Gate-Drain Charge	Q_{gd}	V _{GS} =10V	-	46		nC
Drain-Source Diode Characteristics			•			
Diode Forward Voltage (Note 3)	V _{SD}	V _{GS} =0V,I _S =30A	-		1.2	V
Diode Forward Current (Note 2)	I _S		-	-	60	Α
Reverse Recovery Time	t _{rr}	TJ = 25°C, IF = 30A	-	42		nS
Reverse Recovery Charge	Qrr	di/dt = 100A/µs ^(Note3)	-	66		nC
Forward Turn-On Time	t _{on}	Intrinsic turn-on time is negli	gible (turi	n-on is do	minated b	y LS+LD)

Notes:

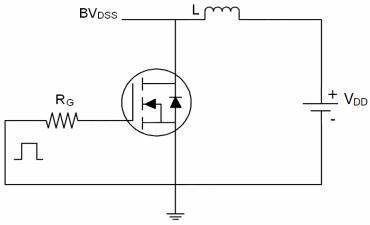
- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- 2. Surface Mounted on FR4 Board, t ≤ 10 sec.
- 3. Pulse Test: Pulse Width ≤ 300µs, Duty Cycle ≤ 2%.
- 4. Guaranteed by design, not subject to production
- 5. E_AS condition: j=25 $^{\circ}\text{C}\,\text{,V}_{DD}\text{=}50\text{V},\text{V}_{G}\text{=}10\text{V},\text{L=}0.5\text{mH,Rg=}25\Omega$

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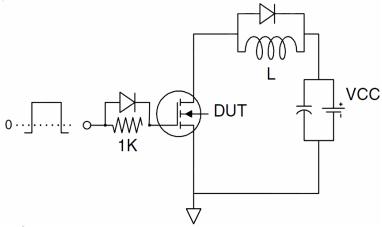


Test Circuit

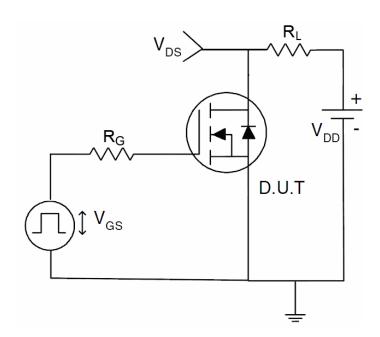
1) E_{AS} test Circuits



2) Gate charge test Circuit



3) Switch Time Test Circuit



Typical Electrical and Thermal Characteristics (Curves)

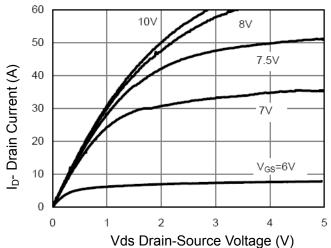


Figure 1 Output Characteristics

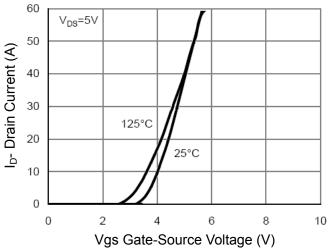


Figure 2 Transfer Characteristics

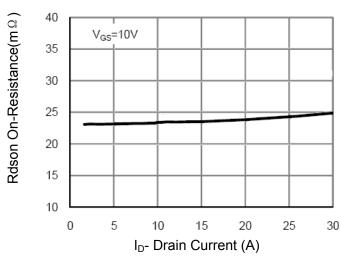


Figure 3 Rdson- Drain Current

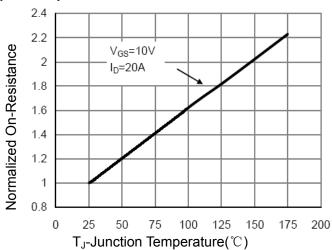


Figure 4 Rdson-Junction Temperature

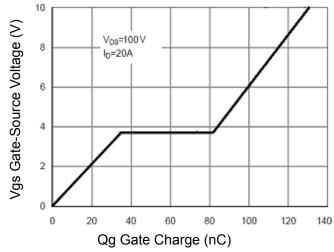


Figure 5 Gate Charge

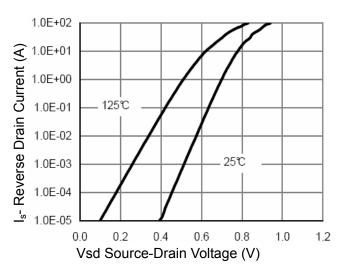
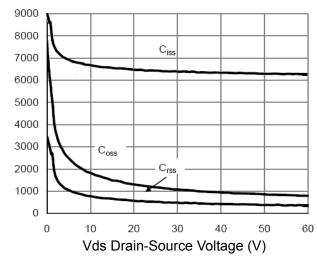


Figure 6 Source- Drain Diode Forward

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C Capacitance (pF)



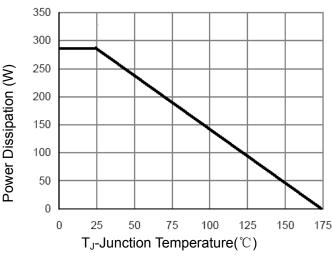
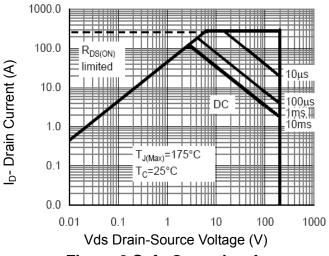


Figure 7 Capacitance vs Vds

Figure 9 Power De-rating



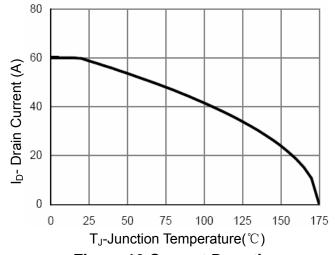


Figure 8 Safe Operation Area

Figure 10 Current De-rating

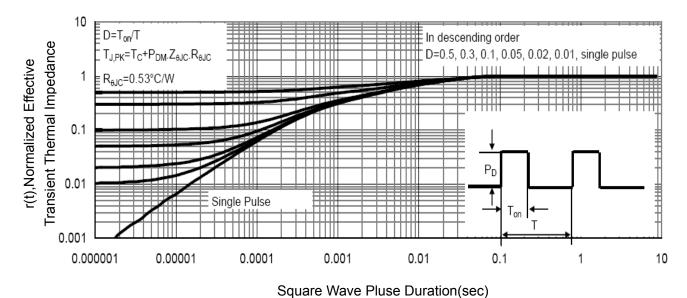
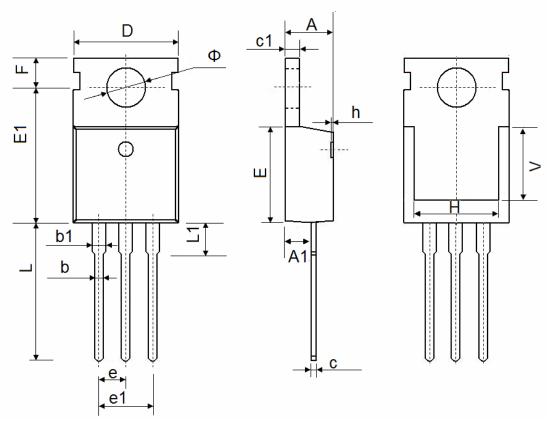


Figure 11 Normalized Maximum Transient Thermal Impedance

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TO-220-3L Package Information



Symbol	Dimensions	In Millimeters	Dimensions In Inches		
Symbol	Min.	Max.	Min.	Max.	
Α	4.400	4.600	0.173	0.181	
A1	2.250	2.550	0.089	0.100	
b	0.710	0.910	0.028	0.036	
b1	1.170	1.370	0.046	0.054	
С	0.330	0.650	0.013	0.026	
c1	1.200	1.400	0.047	0.055	
D	9.910	10.250	0.390	0.404	
E	8.9500	9.750	0.352	0.384	
E1	12.650	12.950	0.498	0.510	
е	2.540	TYP.	0.100 TYP.		
e1	4.980	5.180	0.196	0.204	
F	2.650	2.950	0.104	0.116	
Н	7.900	8.100	0.311	0.319	
h	0.000	0.300	0.000	0.012	
L	12.900	13.400	0.508	0.528	
L1	2.850	3.250	0.112	0.128	
V	7.500 REF.		0.295 REF.		
Ф	3.400	3.800	0.134	0.150	



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